

Features

- Trench Power LV MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low $R_{DS(ON)}$
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)
- Moisture Sensitivity Level 1

Maximum Ratings

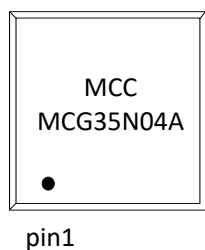
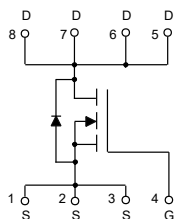
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 3.1°C/W Junction to Case⁽²⁾

| Parameter | Symbol | Rating | Unit |
|-------------------------------------|----------|--------|------|
| Drain-Source Voltage | V_{DS} | 40 | V |
| Gate-Source Voltage | V_{GS} | ±20 | V |
| Continuous Drain Current | I_D | 35 | A |
| Pulsed Drain Current ⁽³⁾ | I_{DM} | 160 | A |
| Total Power Dissipation | P_D | 40 | W |
| Single Pulsed Avalanche Energy | E_{AS} | 120 | mJ |

Note:

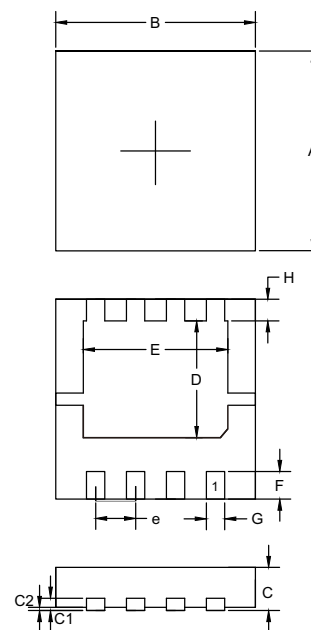
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. Surface Mounted on 1 in² pad area, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300us, Duty cycle ≤ 2%.

Internal Structure and Marking Code



N-CHANNEL MOSFET

DFN3333



| DIM | DIMENSIONS | | | | NOTE |
|-----|------------|-------|------|------|------|
| | INCHES | | MM | | |
| | MIN | MAX | MIN | MAX | |
| A | 0.126 | 0.130 | 3.20 | 3.30 | |
| B | 0.126 | 0.130 | 3.20 | 3.30 | |
| C | 0.030 | 0.033 | 0.75 | 0.85 | |
| C1 | 0.007 | 0.009 | 0.18 | 0.22 | |
| C2 | --- | 0.002 | --- | 0.05 | |
| D | 0.071 | 0.079 | 1.80 | 2.00 | |
| E | 0.087 | 0.098 | 2.20 | 2.50 | |
| F | 0.016 | 0.020 | 0.40 | 0.50 | |
| G | 0.010 | 0.014 | 0.25 | 0.35 | |
| H | 0.012 | 0.016 | 0.30 | 0.40 | |
| e | 0.024 | 0.028 | 0.60 | 0.70 | |

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|---------------------------------|---------------|--|-----|------|-----------|------------|
| Static Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS}=0V, I_D=250\mu A$ | 40 | | | V |
| Gate-Source Leakage Current | I_{GSS} | $V_{DS}=0V, V_{GS}=\pm 20V$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=40V, V_{GS}=0V$ | | | 1 | μA |
| Gate-Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$ | 1 | 1.5 | 2.5 | V |
| Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS}=10V, I_D=20A$ | | 6.5 | 8 | m Ω |
| | | $V_{GS}=4.5V, I_D=10A$ | | 8.7 | 13 | m Ω |
| Diode Characteristics | | | | | | |
| Continuous Body Diode Current | I_S | | | | 35 | A |
| Diode Forward Voltage | V_{SD} | $V_{GS}=0V, I_S=20A$ | | | 1.2 | V |
| Reverse Recovery Time | t_{rr} | $I_F=20A, di_F/dt=100A/\mu s$ | | 15 | | ns |
| Reverse Recovery Charge | Q_{rr} | | | 2.3 | | nC |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=20V, V_{GS}=0V, f=1MHz$ | | 1860 | | pF |
| Output Capacitance | C_{oss} | | | 256 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 205 | | |
| Total Gate Charge | Q_g | $V_{DS}=20V, V_{GS}=10V, I_D=20A$ | | 46.7 | | nC |
| Gate-Source Charge | Q_{gs} | | | 8 | | |
| Gate-Drain Charge | Q_{gd} | | | 11.6 | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DS}=20V, V_{GEN}=10V, R_G=3\Omega, R_L=1\Omega, I_{DS}=2A$ | | 10 | | ns |
| Turn-On Rise Time | t_r | | | 21 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 36 | | |
| Turn-Off Fall Time | t_f | | | 25 | | |

Curve Characteristics

Fig. 1 - Typical Output Characteristics

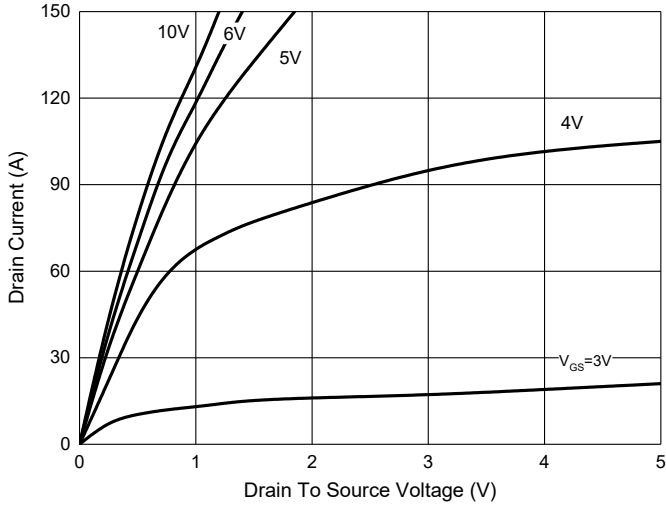


Fig. 2 - Transfer Characteristics

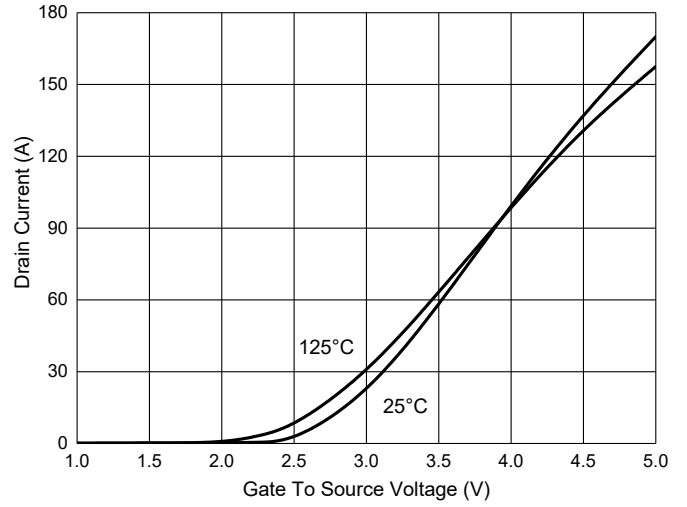


Fig. 3 - $R_{DS(ON)} - I_D$

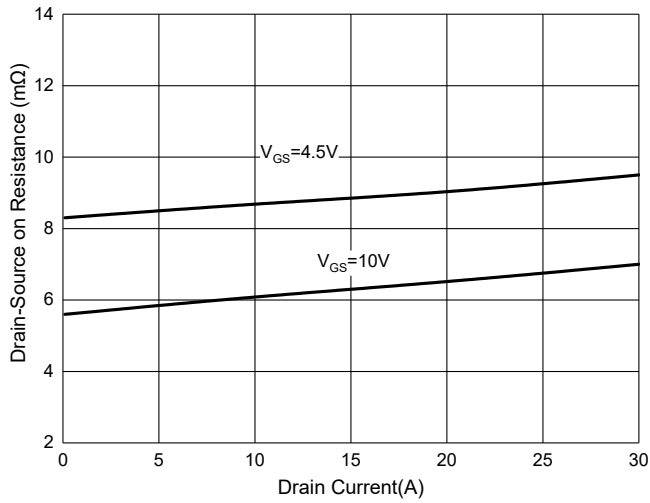


Fig. 4 - Normalized On Resistance Characteristics

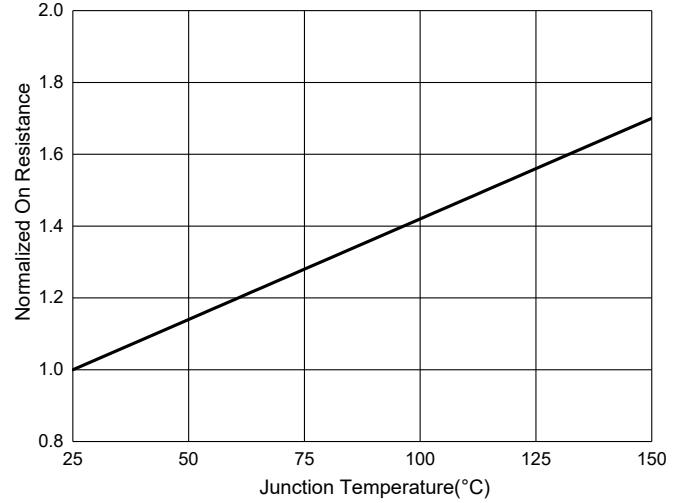


Fig. 5 - Capacitance Characteristics

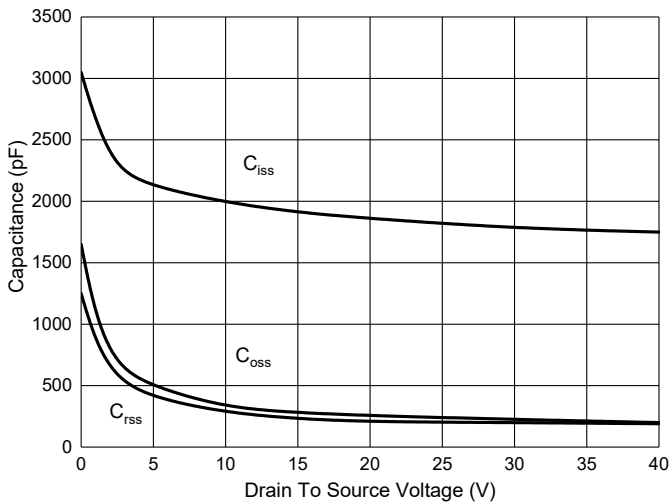
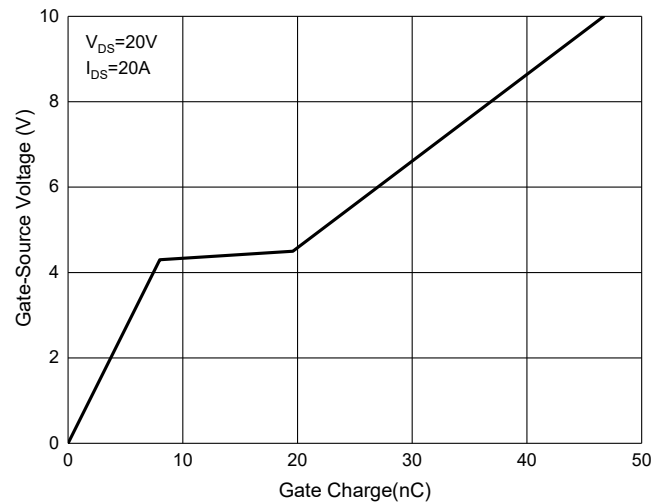
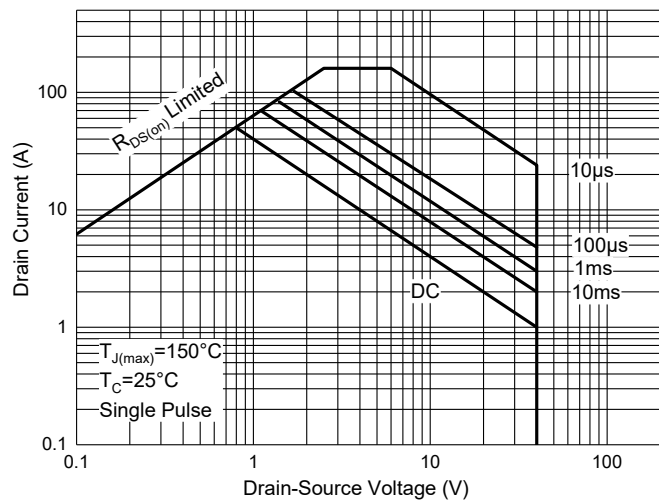


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Safe Operation Area



Ordering Information

| Device | Packing |
|----------------|-----------------------|
| Part Number-TP | Tape&Reel: 5Kpcs/Reel |

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